





20 Minute Introduction to IXS



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Set the scene for discussion

Mention some useful common points - essentially for reference Bring up methodological aspects - what might be changed Touch on some possible scientific areas of interest to be addressed/expanded upon

Followed with contributions from participants: (DeBeer -> Emission Spectroscopy, HR-RIXS, NIS) Monaco -> NRIXS & HR- RIXS Cramer -> NIS Chumakov -> NIS vs IXS, Nuclear Analyzer (?) Sinha -> Phonon form factor



Two Main Quantities:

Energy Transfer

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$$\mathbf{E} = \mathbf{E}_1 - \mathbf{E}_2 = \hbar \boldsymbol{\omega}$$

Note: For Resonant Scattering E_1 and E_2 and Polarization are also important

Momentum Transfer

$$\mathbf{Q} = \mathbf{k}_2 - \mathbf{k}_1$$

$$|\mathbf{Q}| \approx \frac{4\pi}{\lambda_i} \sin\left(\frac{\Theta_{scatt}}{2}\right)$$

Periodicity $d = \frac{2\pi}{|\mathbf{Q}|}$





The IXS Spectrometer An Optics Problem

Main Components









Common Features

Photon In -> Photon Out

Measure intensity as a function of energy transfer (Mostly...)

Measure at fixed (range of) scattering angles -> Q typically well defined

Dividing Features

Energy Resolution & Transfer Resonant vs. Non-Resonant (Cross section, Resolution, Q) Electronic vs. Nuclear

Momentum (Q) Resolution and Transfer

Sample Geometries (layers, surfaces, micro-crystals, liquids, allowable sample volume) Sample Environments (T, P, H, E, ...)

















Table Of IXS Techniques/Applications

Technique	Comment	Energy Scale	Information		
X-Ray Raman	IXS version of xafs High resolution case?	E _{in} >4 keV ΔE~500-1000 eV Res: ~eV	Chemical Bonding		
X-Ray Emission	High resolution case?	E _{in} >4 keV ΔE~1-100 eV Res: ~eV	Chemical Bonding		
RIXS Resonant IXS	High Rate Somewhat Complicated	E _{in} >4 keV ΔE ~ 1-50 eV Res: ~0.1-1 eV	Electronic & Magnetic Structure		
HR - RIXS High Res. Resonant IXS	To Be Developed Analyzer a problem	E _{in} ~ >4 keV ΔE ~ 0.1-10 eV Res: 1-20 meV?	Electronic & Magnetic Structure		
NRIXS Non-Resonant IXS	Low Rate Simpler Interpretation	E _{in} ~10 keV ΔE ~ <1-50 eV Res: 20-200 meV	Electronic Structure		
IXS High-Resolution IXS	Larger Instrument Also: Nuclear Analyzer	E _{in} ~16-26 keV ΔE ~ <1-100 meV Res: 1-3 meV, (<~0.1meV?)	Phonon Dispersion Liquid Excitations		
NIS Nuclear IXS	Atom Specific Via Mossbauer Nuclei	E _{in} ~ 14-25 keV ΔE ~ 1-100 meV Resolution: .~0.5 meV	Element Specific Phonon Density of States (DOS)		

Note: ΔE = Typical Energy Transfer (Not Resolution)





Relevance to the XFEL-O

XFEL-O Characteristics

Hard X-Ray: 5 - 25 keV (higher?) (~6% scan range)
Extreme flux in a small bandwidth: ~5x10¹⁴/s in 5 meV
3 to 4 orders of magnitude more photons/s/meV than 3rd gen
1 to 10 times 3rd gen flux into Si (111) but into a few meV
1-2 MHz Pulse rate, pulse width ~0.5 ps (pump probe)
Mostly Coherent: small focal spot sizes possible (?)

"3 to 4 orders of magnitude more photons/s/meV than 3rd gen"

- -> Incredible potential for experiments Flux/count-rate multiplier New geometries (standing waves?)
- "1 to 10 times 3rd gen flux into Si (111) but into a few meV" -> Many (most) samples will not survive very long, esp. w/focusing

Optics/Detectors downstream of the sample and/or step through the sample and/or choose the right sample





Absolute Energy Matters (generally higher is better)

SPring

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Plot shows relative signal for a thicker (10, 100 um) sample.

Radiation damage scales similarly (x factor of energy - so slower) Higher energy also better for penetration into sample environments, & Q range Higher energy worse for Q Resolution AQRB





Formal Dynamic Structure Factor

Measured Intensity is proportional to the Dynamic Structure Factor $S(\mathbf{Q}, \omega)$

$$I_{scattered} \propto \frac{d^2 \sigma}{d\Omega d\omega} = r_e^2 \left(e_2^* \bullet e_1 \right)^2 \frac{\omega_2}{\omega_1} S(\mathbf{Q}, \omega_1, \omega_2)$$

$$S(\mathbf{Q},\omega) = \frac{1}{2\pi\hbar} \int dt \ e^{-i\omega t} \int d\mathbf{r} \int d\mathbf{r}' \ e^{i\mathbf{Q} \cdot (\mathbf{r} - \mathbf{r}')} \langle \rho(\mathbf{r}',t)\rho(\mathbf{r},t=0) \rangle \qquad \text{Dynamical Density Correlation} \\ (FT of the Dynamical Pair Dist.)$$

$$= N \sum_{\mathbf{q}} \sum_{Modes} \left| \sum_{\substack{d \\ Aioms \\ l \in ell}} \frac{f_d(\mathbf{Q})}{\sqrt{2M_d}} \ e^{-W_d(\mathbf{Q})} \mathbf{Q} \cdot \mathbf{e}_{\mathbf{q}jd} \ e^{i\mathbf{Q} \cdot \mathbf{x}_d} \right|^2 \delta_{(\mathbf{Q}-\mathbf{q}),\tau} F_{\mathbf{q}j}(\omega) \qquad \text{Phonons}$$

$$= \sum_{\lambda,\lambda'} p_\lambda \left| \langle \lambda' | \sum_{\substack{electrons \\ j}} e^{i\mathbf{Q} \cdot \mathbf{r}_j} | \lambda \rangle \right|^2 \delta(E_\lambda' - E_\lambda - \hbar\omega) \qquad \text{Coupling to excitations}$$

$$= \frac{1}{\pi} \frac{1}{1 - e^{-\hbar\omega/k_BT}} \operatorname{Im} \{-\chi(\mathbf{Q},\omega)\} = \frac{1}{\pi} \frac{1}{1 - e^{-\hbar\omega/k_BT}} \frac{1}{\nu(\mathbf{Q})} \operatorname{Im} \{-\varepsilon^{-1}(\mathbf{Q},\omega)\} \qquad \text{Generalized}$$





Phonon Spectroscopy S(Q,w) for Q>0

Normal modes of vibration (3N modes/Q in periodic materials) For simpler materials & specific examples of complexity: Well explored experimentally (60's on) Calculations have now largely caught up to that work

Frontiers in Phonon Physics

Coupling to meso/macro scale order & disorder. Phonon-Phonon scattering / anharmonicity Coupling to magnetism & orbital order Low dimensional systems Precision investigation for epc in complex materials

Ferroelectrics... Many, Relaxors Multiferroics etc

Many Superconductors etc

Frontiers for BOTH experiment and calculation

IXS Offers: Clean data, Small samples, Good Q Resolution



ChPrecision Phonons in Complex Materials

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There remain a number of cases (large unit cell, mixed heavy/ light atoms) where phonon measurements can benefit from improved flux/Q resolution



Immediate Question on Presentation Is there fine structure?





NRIXS

Non-Resonant Inelastic X-Ray Scattering

Typically ~100 meV resolution, targeting low energy (eV-scale) electronic excitations: d-d, orbitons, crystal field?, mixed? subtle band-structure effects, gaps (plasmons?) Large Q acceptance to get intensity (50x50 vs 5x5 mrad²)

Improve resolution to allow better spectra, closer to the elastic line, and to avoid phonons (note 2-phonon will limit smallest cross section)



SIXS

Complex orbital excitation Combining spin/hole motion Schlappa, et al, Nat 2012









Momentum Transfers

Large Q (>20 nm⁻¹): Detailed atomic structure Beyond Dipole Approximation (NRIXS)

Low to mid Q (<1 to >10 nm⁻¹): Macro/micro crossover (esp. disordered materials)

Low Q limit (as low as reasonable): Used to approximate inaccessible macroscopic quantities Sound velocity, viscosity

Q is MOSTLY exactly what you want for periodic systems







Avoiding Q

Specific Potential Exceptions where "Q" is maybe less useful:

- 1. Extreme anharmonic effects / phonon localization (Solitons)
- 2. Scattering near defects (e.g. dilute resonant impurities)
- 3. Disordered Materials

Basically: when phonons are not a good basis set

Option:

Fourier transform S(Q,w) into (r,t) space (or (r,w) space) e.g. van Hove Correlation G(r,t) (or, similar, impulse response)









Access to Transverse Dynamics (atomic dynamics of disordered materials)

Fundamental limitation: $S(\mathbf{Q}, w)$ directly measures only longitudinal dynamics

$$S(\mathbf{Q},\omega) = \frac{1}{2\pi\hbar} \int dt \ e^{-i\omega t} \int d\mathbf{r} \int d\mathbf{r}' \ e^{i\mathbf{Q}\cdot(\mathbf{r}-\mathbf{r}')} \langle \rho(\mathbf{r}',t)\rho(\mathbf{r},t=0) \rangle$$

(For crystals can get transverse dynamics near a Bragg point)

This is a serious limitation for basic physics:

Liquids and glasses: have significant contribution of transverse dynamics Boson peak = (probably) transverse dynamics

Can see (weak) signatures of transverse dynamics in S(Q,w) but they tend to be blurred and hard to isolate. Some way to isolate these experimentally would probably allow large advance in understanding disordered (technologically relevant??) materials.

> HR-RIXS? Thoughts: IXS with Correlation? Confined fluids



Just One Example: Transverse Dynamics in Liquid Bi



Data: Inui et al, PRB 2015 Calcs: Ropo, Akolo, Jones (submitted)







Ultra-High Resolution IXS

Potentially interesting for quasi-elastic scattering (viscosity) and phonon linewidths

Monochromators have been shown, with work to go to ~0.1 meV and one hopes for smaller. Analyzers an issue. (Can consider a post-sample-collimation setup - Shvyd'ko)

Consider nuclear analyzer.... (Chumakov, et al, PRL 1996)

Ε	E Iso. æV]	τ [ns]	Г	a	J _{ex}	$\mathbf{J}_{\mathbf{g}}$	σ	σ σ _e n	β_{opt}	Effective Bandwidth [µeV]				
[keV]			[neV]				n			0ns	1ns	2ns	5ns	10ns
8.41	¹⁶⁹ Tm	5.8	114	268	1.5	0.5	38	3.4	8.0	0.65	0.31	0.17	0.04	0.01
9.41	⁸³ Kr	212	3.1	19.6	3.5	4.5	104	0.84	133	0.19	0.16	0.14	0.10	0.06
14.41	⁵⁷ Fe	141	4.7	8.2	1.5	0.5	383	0.59	439	1.52	0.66	0.41	0.18	0.11
21.54	¹⁵¹ Eu	14.0	47.0	28.6	3.5	2.5	25	0.87	28.6	0.67	0.37	0.23	0.09	0.03
22.49	$^{149}\mathrm{Sm}$	10.3	64.1	50	2.5	3.5	6.8	0.73	11.4	0.30	0.20	0.14	0.06	0.02
23.88	119 Sn	25.6	25.7	5.1	1.5	0.5	210	0.26	590	10.5	1.10	0.67	0.29	0.13
25.66	¹⁶¹ Dy	40.7	16.2	2.9	2.5	2.5	95	0.66	152	1.17	0.55	0.34	0.14	0.07

Lossy on 0.1 meV scale, Better on ~10 ueV scale...





RIXS



For d-electron physics : L-edge much preferred. Spin, orbital, charge order all accessible.

Relevance: magnons, orbitons, mixed excitations -> calcs needed but getting better

Just for resonant enhancement, either OK (K edge may be larger)





High Resolution RIXS

In present geometries, basically analyzer limited in hard x-ray region as need to match analyzer lattice constant to resonance energy. Materials include quartz and sapphire (analyzers: Yavas et al, jsr2015, nim 2007).



Quartz anal, 2m radius (100mm diam) Expect improvement to ~5 meV is straightforward To meV, or sub-meV, is not so clear, but probably...

0

Energy transfer (meV)

50

100

 $\zeta = 1.9$

 $\zeta = 1.1$

Interest: coupling to magnetism, density waves, possibly alternative view of epc (Devereaux and others) resonance specificity

15

-100

-50

Counts (Hz)





Some Specific Issues/Goals for this workshop

Goal (?):

Come up with high-profile experiments addressing (broadly? societally?) relevant science that will help get the machine funded.

Targeted studies probably required due to beam time and instrumentation (manpower and money) limits

Especially true for IXS: *multiple* big spectrometers probably not an (immediate) option...

Note: pump-probe not addressed here...





Optics Questions & Challenges

Method for meV-resolution IXS: Spherical Analyzers? Post-Sample Collimation (YS&+spectrograph?). sample clear aperture (for sample environment -> larger is better) required beam size (larger is easier, maybe better for rad damage) allowable beam projection/ sample thickness at finite Q resolution function -> FWHM? (PSC tail can be better) parallelization (Q, E-spectrograph (ys)) absolute energy: higher is better

What about low-resolution expts: NRIXS: Desire 5-10 meV res with sharp tail Emission? X-Ray Raman?

Sufficiently flexible spectrometer design(s) without sacrificing capability

Development of high resolution RIXS analyzers 5 meV probably OK (work required), 1 meV maybe.

Development of ultra-high resolution non-resonant spectrometer Mono? PSC optics? Nuclear Analyzer?

> Expect incident beam optics to be LN2 cooled Never forget the fight against radiation damage...





Experimental Suggestions

Build on present research programs... handle with care!

- 1. Using standing waves to investigated phonons
- 2. Using a meV spectrometer to probe sub-ueV linewidths
- 3. Reminder of High Pressure challenges and dedication







(7)

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 $= I_0 \frac{k_f}{k} \frac{N}{A_s} \sum \left\{ |f_\sigma(\boldsymbol{K})|^2 + |f_\sigma(\boldsymbol{K}')|^2 + 2 \operatorname{Re}\left[e^{i\chi} f_\sigma(\boldsymbol{K}) f_\sigma^*(\boldsymbol{K}') \right] \right\} G(\boldsymbol{q}, \sigma) ,$

Coherent 2-Beam Excitation

(Standing Waves)



Include Bragg Excitation (or specular). Look at surface (deposited layer) or at bulk.

Change angle - change standing wave maxima

(Formal phonon polarization viewpoint: Kohl, pss (1985)) $\frac{\mathrm{d}^{2}I}{\mathrm{d}\mathcal{Q}\,\mathrm{d}\mathcal{E}} = \frac{I_{0}}{2}\frac{k_{T}}{k}\frac{N}{2s}\sum_{q\sigma}|f_{\sigma}(\mathbf{K}) + \mathrm{e}^{-i\chi}f_{\sigma}(\mathbf{K}')|^{2}G(q,\sigma) = 0$

Driving Science: Interface/surface behavior can lead to remarkable properties Single Layer in Specular GIXS, Multilayers structure

e.g. insulators that superconduct (LaAlO₂/STO) Reyren, Science (2007) High-Tc (100K!) of FeSe on STO - Ge Nat Mtl. (2015) Understanding how water surfs on graphene

> Need High (near unity) reflectivity Brilliance Hungry Expt (small beam & well collimated)





Multilayer Less Demanding Example - Now In Progress





Select Position on RC Allow focus onto phonons in Si or in W





(More) Extreme Conditions



Faster Experiments help a lot when in marginally stable conditions

Sound Velocity. Viscosity.

SPring 8

Using a meV Spectrometer to probe (sub) neV linewidths

Detailed Fundamental Symmetry of a Balance Sample in Thermal Equilibrium

$$\frac{S(\mathbf{Q}, \omega)}{S(\mathbf{Q}, -\omega)} = e^{\hbar\omega/k_BT} \qquad \begin{array}{c} \text{Strictly:} \\ \frac{S(\mathbf{Q}, \omega)}{S(-\mathbf{Q}, -\omega)} = e^{\hbar\omega/k_BT} \end{array}$$

But what if you violate the conditions of thermal equilibrium? i.e.: if you induce a thermal gradient

Boltzmann Transport Theory: $n_s - \overline{n_s} = -\tau_s \frac{\partial \overline{n_s}}{\partial T} v \nabla T$

Small (5%) effect, but direct probe of phonon lifetime for longer lifetimes